

## Features

- SiC MOSFET Technology
- High Blocking Voltage with Low On-resistance
- Avalanche Ruggedness
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant (Note2) ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## Maximum Ratings

- Operating Junction Temperature Range : -55°C to +175°C
- Storage Temperature Range: -55°C to +175°C
- Thermal Resistance: 0.4 °C/W Junction to Case

## Applications

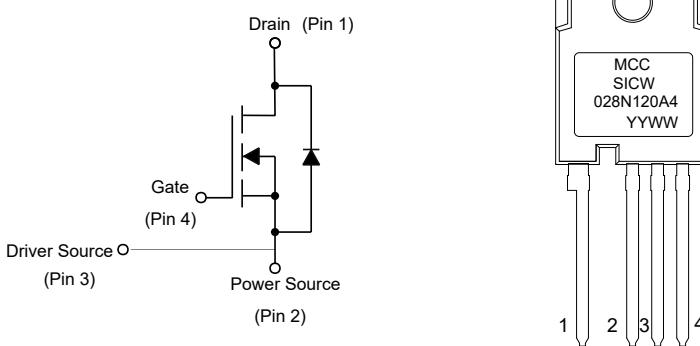
- Solar Inverters
- Switch Mode Power Supplies
- High Voltage DC/DC Converters
- Battery Chargers
- Motor Drives

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	1200	V
Gate-Source Voltage	$V_{GSmax}$	-5/+22	V
Gate-Source Voltage	$V_{GSop}$	-3/+18	V
Continuous Drain Current $V_{GS}=18V$	$I_D$	80	A
		52	
Pulsed Drain Current (Note 3)	$I_{DM}$	320	A
Single Pulse Avalanche Energy (Note4)	$E_{AS}$	1620	mJ
Total Power Dissipation	$P_D$	375	W
		162	

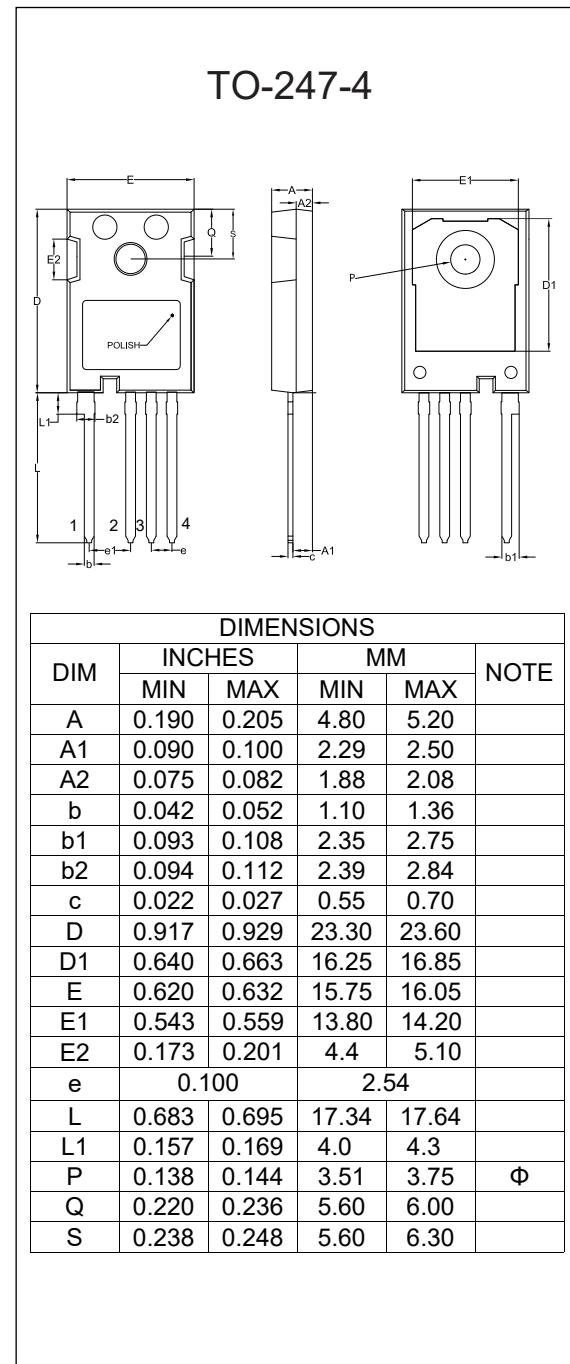
Notes:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. High Temperature Solder Exemptions Applied, see EU Directive Annex 7a.
3. Pulse Test: Pulse Width Limited by  $T_{jmax}$ .
4. EAS Condition: Starting  $T_J=25^\circ C$ ,  $V_{DD}=50V$ ,  $V_{GS}=20V$ ,  $R_g=25\Omega$ ,  $L=10mH$ .

## Internal Structure



## N-CHANNEL MOSFET



**Electrical Characteristics @  $T_j=25^\circ\text{C}$  (Unless Otherwise Specified)**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{GS}=0\text{V}, I_D=250\mu\text{A}$	1200			V
Gate-Source Leakage Current	$I_{GSS}$	$V_{DS}=0\text{V}, V_{GS}=-5/+22\text{V}$			$\pm 250$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=1200\text{V}, V_{GS}=0\text{V}$			100	$\mu\text{A}$
Gate-Threshold Voltage <sup>(Note5)</sup>	$V_{GS(\text{th})}$	$V_{DS}=V_{GS}, I_D=15\text{mA}$	1.5	2.0	3.0	V
Drain-Source On-Resistance <sup>(Note5)</sup>	$R_{DS(\text{on})}$	$V_{GS}=20\text{V}, I_D=40\text{A}$		26	30	$\text{m}\Omega$
		$V_{GS}=18\text{V}, I_D=40\text{A}$		28	35	$\text{m}\Omega$
		$V_{GS}=16\text{V}, I_D=40\text{A}$		32	40	$\text{m}\Omega$
Internal Gate Resistance	$R_g$	$f=1\text{MHz}, V_{AC}=25\text{mV}$		1.5		$\Omega$
<b>Diode Characteristics</b>						
Continuous Body Diode Current <sup>(Note6)</sup>	$I_S$	$V_{GS}=-3\text{V}$		72		A
Diode Forward Voltage <sup>(Note5)</sup>	$V_{SD}$	$V_{GS}=-3\text{V}, I_{SD}=40\text{A}$		4.5		V
Reverse Recovery Time	$t_{rr}$	$V_{GS}=-3/+18\text{V}, I_{SD}=40\text{A}, V_R=800\text{V}, dI_F/dt=400\text{A}/\mu\text{s}$		72		ns
Reverse Recovery Charge	$Q_{rr}$			240		nC
Peak Reverse Recovery Current	$I_{rrm}$			6.2		A
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=1000\text{V}, V_{GS}=0\text{V}, f=1\text{MHz}$ $V_{AC}=25\text{mV}$		3570		$\text{pF}$
Output Capacitance	$C_{oss}$			170		
Reverse Transfer Capacitance	$C_{rss}$			18		
Cross Stored Energy	$E_{oss}$			97		$\mu\text{J}$
Total Gate Charge	$Q_g$	$V_{DS}=800\text{V}, V_{GS}=-3/+18\text{V}$ $I_D=40\text{A}$		168		$\text{nC}$
Gate-Source Charge	$Q_{gs}$			35		
Gate-Drain Charge	$Q_{gd}$			53		
Gate Plateau Voltage	$V_{pl}$			7.1		V
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=800\text{V}, V_{GS}=-3/+18\text{V}, R_{G(\text{ext})}=2.5\Omega, I_{DS}=40\text{A}, L=200\mu\text{H}$		14		$\text{ns}$
Turn-On Rise Time	$t_r$			13		
Turn-Off Delay Time	$t_{d(off)}$			42.5		
Turn-Off Fall Time	$t_f$			11		
Turn-On switching energy	$E_{on}$			223		$\mu\text{J}$
Turn-Off switching energy	$E_{off}$			257		

Notes:

5. Pulse test, pulse width  $\leq 380\mu\text{s}$ .

6. Limited by maximum power dissipation allowed.

## Curve Characteristics

Fig. 1 - Typical Output Characteristic ( $T_J=25^\circ\text{C}$ )

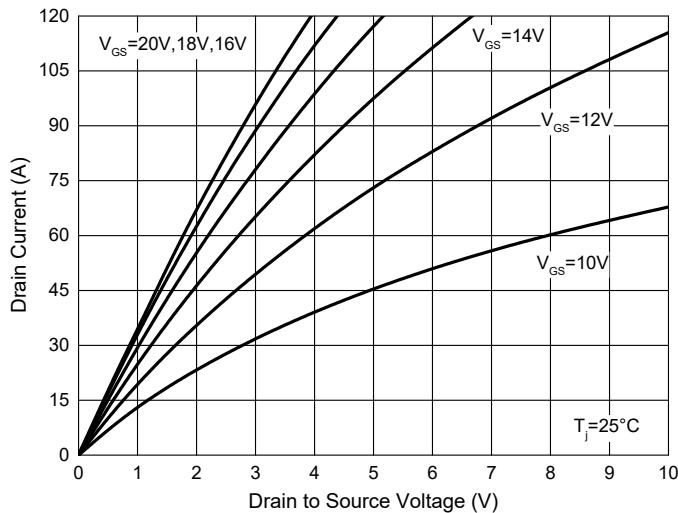


Fig. 2 - Typical Output Characteristic ( $T_J=175^\circ\text{C}$ )

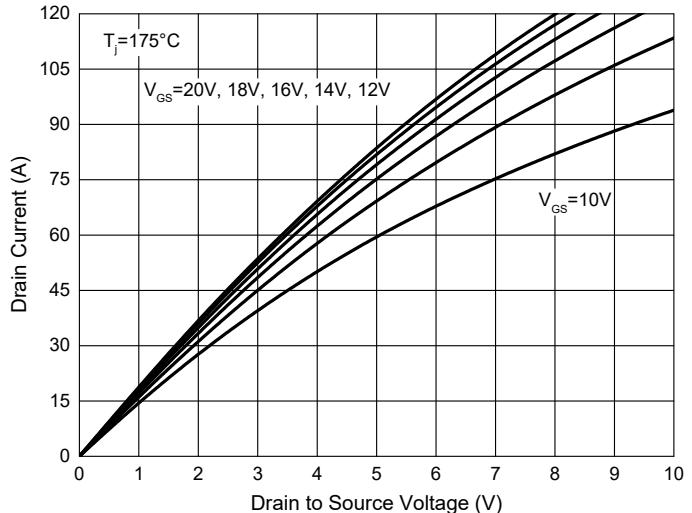


Fig. 3 - Typical Transfer Characteristic

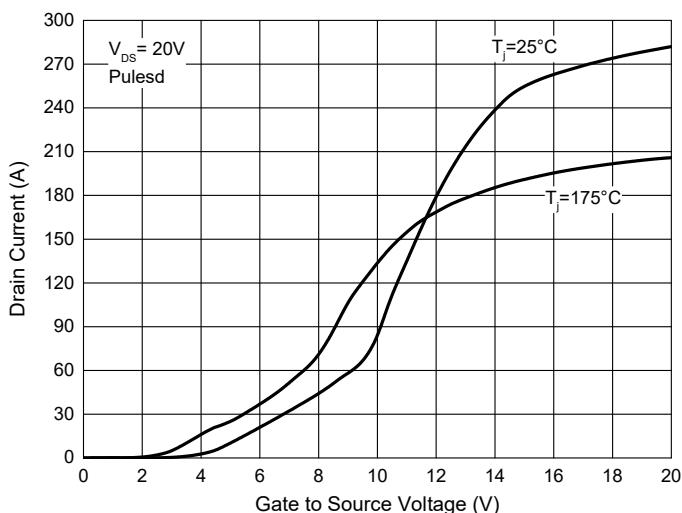


Fig. 4 - On-Resistance vs. Drain Current

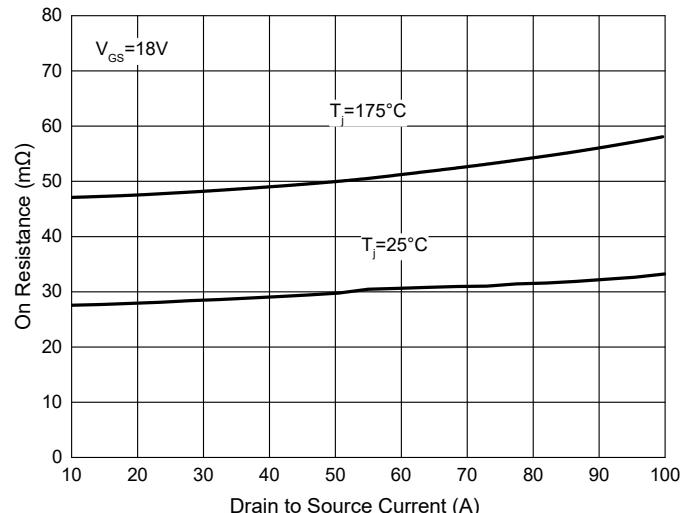


Fig. 5 On-Resistance vs Gate Voltage

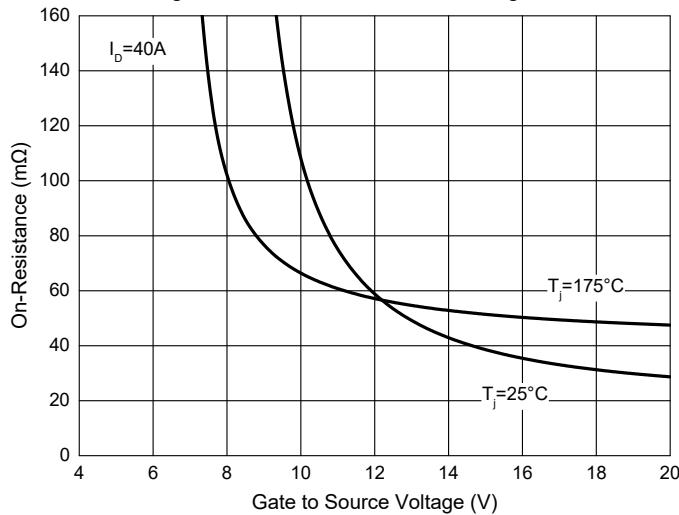
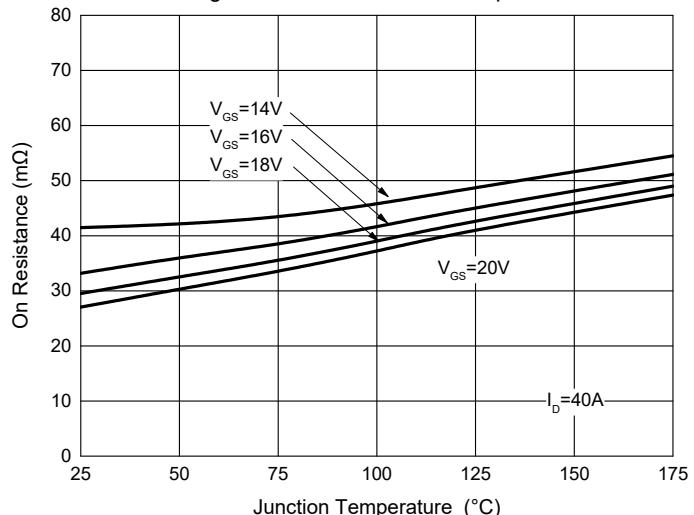


Fig. 6 - On-Resistance vs Temperature



## Curve Characteristics

Fig. 7 - Normalized On-Resistance vs Temperature

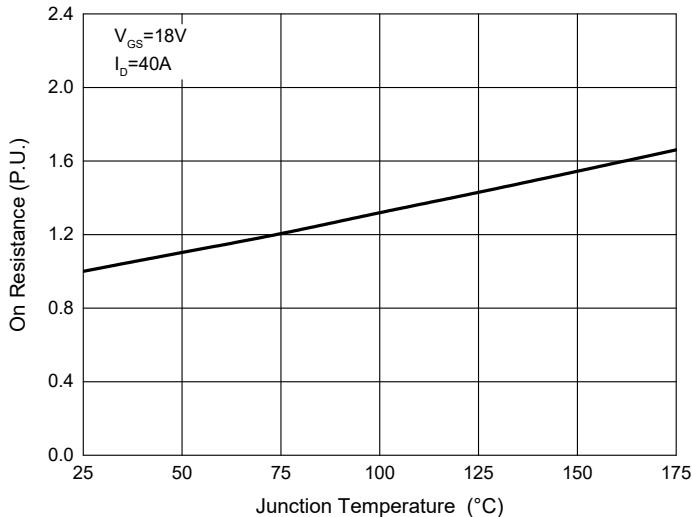


Fig. 8 - Body Diode Characteristic

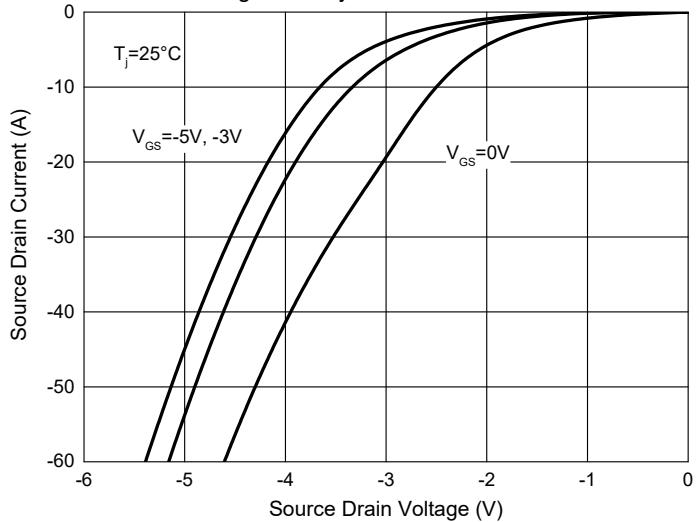


Fig. 9 - Body Diode Characteristic

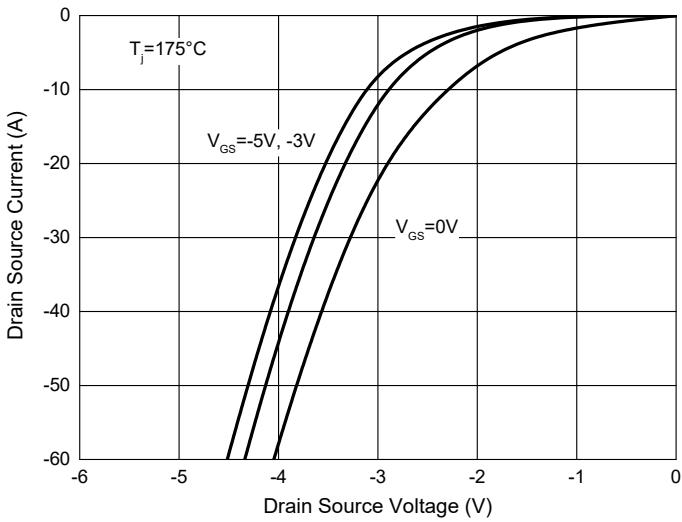


Fig. 10 - Output capacitor stored energy

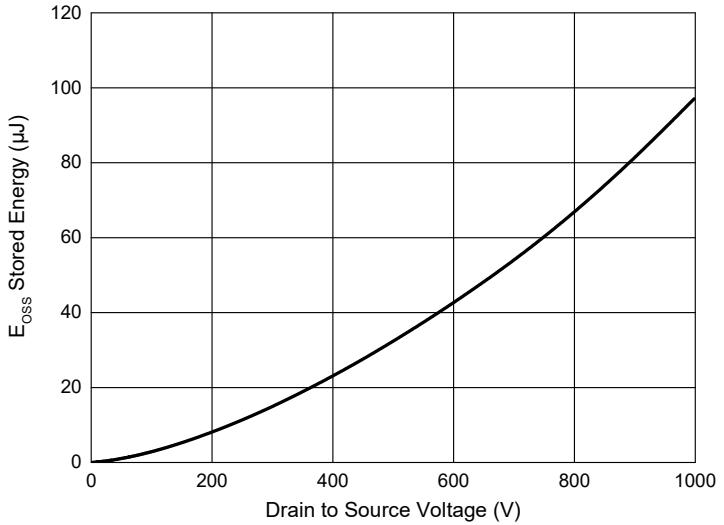


Fig. 11 - Threshold Voltage vs Temperature

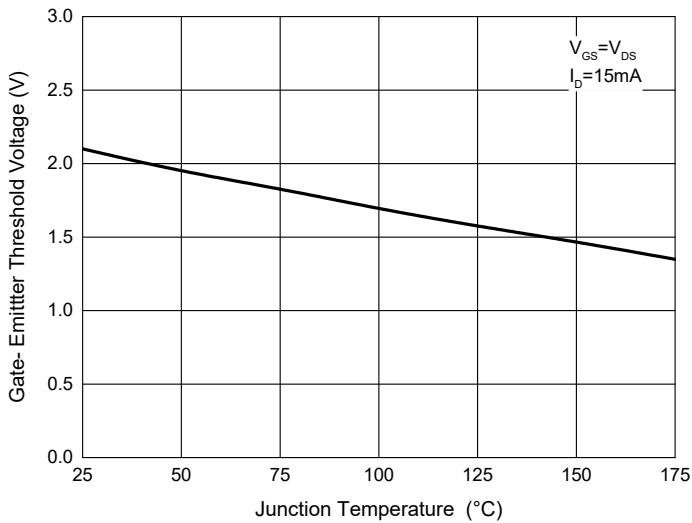
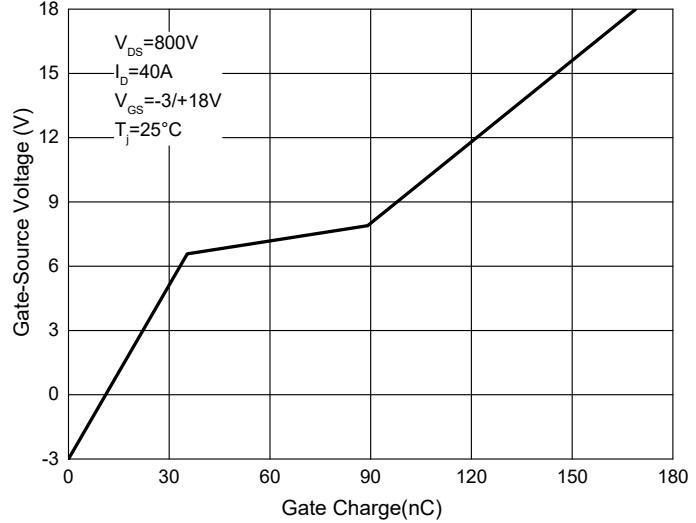


Fig. 12 - Typical Gate Charge



## Curve Characteristics

Fig. 13 - Capacitance Characteristics

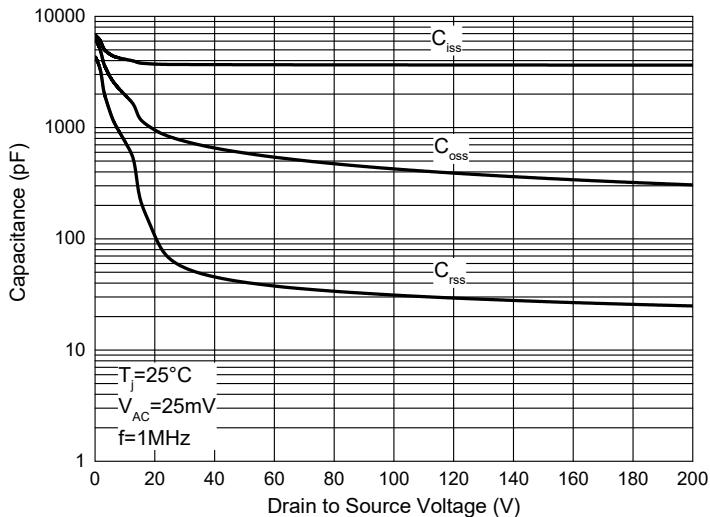


Fig. 14 - Capacitance Characteristics

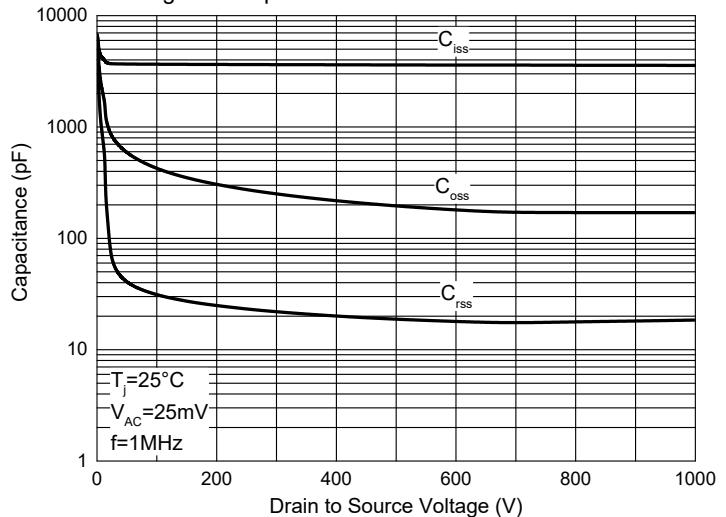


Fig. 15 - Drain Current Derating vs Case Temperature

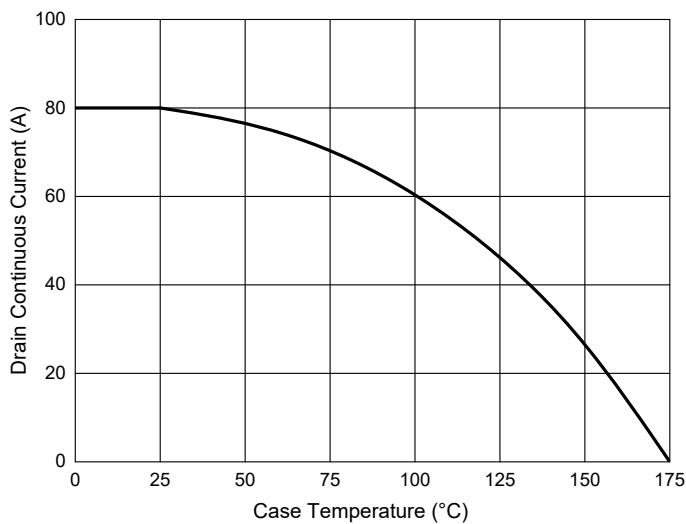


Fig. 16 - Normalized Transient Thermal Impedance

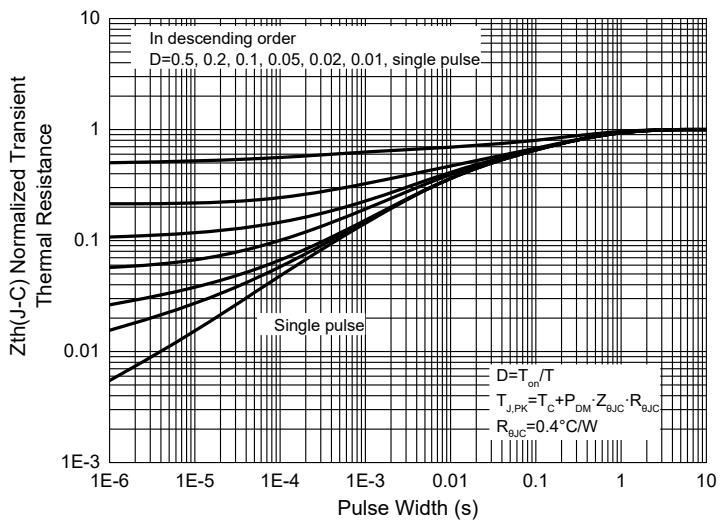


Fig. 17 - Safe Operation Area

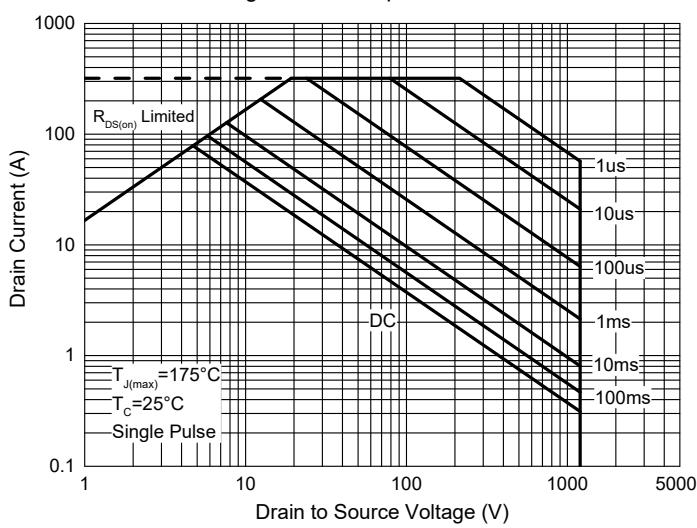
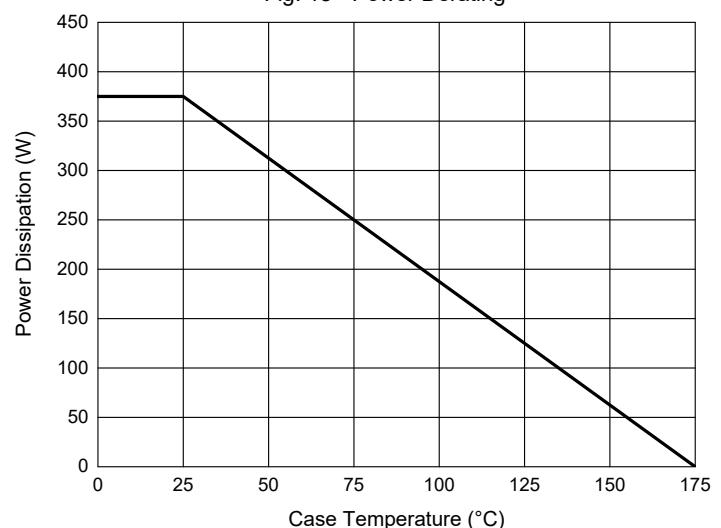


Fig. 18 - Power Derating



## Ordering Information

Device	Packing
SICW028N120A4-BP	Tube:30pcs/Tube, 1.8K/Ctn;

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[G3R40MT12J](#)